

Vishay Semiconductors

High Efficiency LED in Ø 3 mm Tinted Diffused Package



FEATURES

- Standard Ø 3 (T-1) package
- Small mechanical tolerances
- Suitable for DC and high peak current
- · Wide viewing angle
- · Luminous intensity categorized
- Yellow and green color categorized
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC





COMPLIANT

GREEN

(5-2008)**

DESCRIPTION

The TLH.44.. series was developed for standard applications like general indicating and lighting purposes.

It is housed in a 3 mm tinted diffused plastic package. The wide viewing angle of these devices provides a high on-off contrast.

Several selection types with different luminous intensities are offered. All LEDs are categorized in luminous intensity groups. The green and yellow LEDs are categorized additionally in wavelength groups.

That allows users to assemble LEDs with uniform appearance.

APPLICATIONS

- · Status lights
- Off/on indicator
- Background illumination
- · Readout lights
- Maintenance lights
- Legend light

PRODUCT GROUP AND PACKAGE DATA

Product group: LEDPackage: 3 mm

Product series: standard
Angle of half intensity: ± 30°

PARTS TABLE					
PART	COLOR, LUMINOUS INTENSITY	TECHNOLOGY			
TLHP4401	Pure green, I _V > 1 mcd	GaP on GaP			
TLHP4401-AS12Z	Pure green, I _V > 1 mcd	GaP on GaP			
TLHG4400	Green, I _V > 2.5 mcd	GaP on GaP			
TLHG4401	Green, I _V > 4 mcd	GaP on GaP			
TLHG4405	Green, I _V > 6.3 mcd	GaP on GaP			
TLHY4400	Yellow, I _V > 1.6 mcd	GaAsP on GaP			
TLHY4400-AS12Z	Yellow, I _V > 1.6 mcd	GaAsP on GaP			
TLHY4400-AS21	Yellow, I _V > 1.6 mcd	GaAsP on GaP			
TLHY4400-AS21Z	Yellow, I _V > 1.6 mcd	GaAsP on GaP			
TLHY4400-BT12	Yellow, I _V > 1.6 mcd	GaAsP on GaP			
TLHY4400-CS12	Yellow, I _V > 1.6 mcd	GaAsP on GaP			
TLHY4401	Yellow, I _V > 2.5 mcd	GaAsP on GaP			
TLHY4401-AS12	Yellow, I _V > 2.5 mcd	GaAsP on GaP			
TLHY4401-AS12Z	Yellow, I _V > 2.5 mcd	GaAsP on GaP			
TLHY4401-AS21	Yellow, I _V > 2.5 mcd	GaAsP on GaP			
TLHY4405	Yellow, I _V > 6.3 mcd	GaAsP on GaP			
TLHY4405-AS12	Yellow, I _V > 6.3 mcd	GaAsP on GaP			
TLHY4405-AS12Z	Yellow, I _V > 6.3 mcd	GaAsP on GaP			

^{**} Please see document "Vishay Material Category Policy": www.vishay.com/doc?99902



PARTS TABLE		
TLHY4405-BT12Z	Yellow, I _V > 6.3 mcd	GaAsP on GaP
TLHY4405-MS12	Yellow, I _V > 6.3 mcd	GaAsP on GaP
TLHO4400	Soft orange, I _V > 1.6 mcd	GaAsP on GaP
TLHO4400_AS12Z	Soft orange, I _V > 1.6 mcd	GaAsP on GaP
TLHO4400-MS12Z	Soft orange, I _V > 1.6 mcd	GaAsP on GaP
TLHR4400	Red, I _V > 1.6 mcd	GaAsP on GaP
TLHR4400-AS12	Red, I _V > 1.6 mcd	GaAsP on GaP
TLHR4400-AS12Z	Red, I _V > 1.6 mcd	GaAsP on GaP
TLHR4400-AS21Z	Red, I _V > 1.6 mcd	GaAsP on GaP
TLHR4400-MS12Z	Red, I _V > 1.6 mcd	GaAsP on GaP
TLHR4401	Red, I _V > 2.5 mcd	GaAsP on GaP
TLHR4401-AS12Z	Red, I _V > 2.5 mcd	GaAsP on GaP
TLHR4401-LS12Z	Red, I _V > 2.5 mcd	GaAsP on GaP
TLHR4405	Red, I _V > 6.3 mcd	GaAsP on GaP
TLHR4405-AS12	Red, I _V > 6.3 mcd	GaAsP on GaP
TLHR4405-AS21	Red, I _V > 6.3 mcd	GaAsP on GaP
TLHR4407	Red, I _V = (4 to 12.5) mcd	GaAsP on GaP
TLHR4407-MS12Z	Red, I _V = (4 to 12.5) mcd	GaAsP on GaP

ABSOLUTE MAXIMUM RATINGS ($T_{amb} = 25$ °C, unless otherwise specified) TLHG440. , TLHP440. , TLHP440. , TLHP440.					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		V_{R}	6	V	
DC Forward current		I _F	30	mA	
Surge forward current	t _p ≤ 10 μs	I _{FSM}	1	A	
Power dissipation	T _{amb} ≤ 60 °C	P _V	100	mW	
Junction temperature		T _j	100	°C	
Operating temperature range		T _{amb}	- 40 to + 100	°C	
Storage temperature range		T _{stg}	- 55 to + 100	°C	
Soldering temperature	$t \le 5$ s, 2 mm from body	T _{sd}	260	°C	
Thermal resistance junction/ ambient		R _{thJA}	400	K/W	

OPTICAL AND ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified) TLHR440. , RED							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
		TLHR4400	I _V	1.6	3		mcd
1)	I _F = 10 mA	TLHR4401	I _V	2.5	5		mcd
Luminous intensity 1)	IF = 10 IIIA	TLHR4405	I _V	6.3	10		mcd
		TLHR4407	I _V	4		12.5	mcd
Dominant wavelength	I _F = 10 mA		λ_{d}	612		625	nm
Peak wavelength	I _F = 10 mA		λ_{p}		635		nm
Angle of half intensity	I _F = 10 mA		φ		± 30		deg
Forward voltage	I _F = 20 mA		V_{F}		2	3	V
Reverse voltage	I _R = 10 μA		V_{R}	6	15		V
Junction capacitance	V _R = 0, f = 1 MHz		C _j		50		pF

Note:

1) In one packing unit I_{Vmin.}/I_{Vmax.} ≤ 0.5



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OPTICAL AND ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified) TLHO440, SOFT ORANGE							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous intensity 1)	I _F = 10 mA	TLHO4400	I _V	1.6	4		mcd
Dominant wavelength	I _F = 10 mA		λ_{d}	598		611	nm
Peak wavelength	I _F = 10 mA		λ_{p}		605		nm
Angle of half intensity	I _F = 10 mA		φ		± 30		deg
Forward voltage	I _F = 20 mA		V_{F}		2.4	3	V
Reverse voltage	I _R = 10 μA		V_{R}	6	15		V
Junction capacitance	$V_B = 0$, $f = 1$ MHz		Ci		15		pF

Note:

¹⁾ In one packing unit $I_{Vmin.}/I_{Vmax.} \le 0.5$

OPTICAL AND ELECTRICAL CHARACTERISTICS ($T_{amb} = 25 ^{\circ}C$, unless otherwise specified) TLHY440., YELLOW							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
		TLHY4400	Ι _V	1.6	3		mcd
Luminous intensity 1)	$I_F = 10 \text{ mA}$	TLHY4401	Ι _V	2.5	5		mcd
		TLHY4405	Ι _V	6.3	10		mcd
Dominant wavelength	I _F = 10 mA		λ_{d}	581		594	nm
Peak wavelength	I _F = 10 mA		λ_{p}		585		nm
Angle of half intensity	I _F = 10 mA		φ		± 30		deg
Forward voltage	I _F = 20 mA		V _F		2.4	3	V
Reverse voltage	I _R = 10 μA		V_R	6	15		V
Junction capacitance	V _R = 0, f = 1 MHz		C _j		50		pF

Note:

 $^{^{1)}}$ In one packing unit $I_{Vmin.}/I_{Vmax.} \leq 0.5$

OPTICAL AND ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified) TLHG440., GREEN							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
		TLHG4400	Ι _V	2.5	4		mcd
Luminous intensity 1)	I _F = 10 mA	TLHG4401	Ι _V	4	6		mcd
		TLHG4405	I _V	6.3	12		mcd
Dominant wavelength	I _F = 10 mA		λ_{d}	562		575	nm
Peak wavelength	I _F = 10 mA		λ_{p}		565		nm
Angle of half intensity	I _F = 10 mA		φ		± 30		deg
Forward voltage	I _F = 20 mA		V_{F}		2.4	3	V
Reverse voltage	I _R = 10 μA		V_{R}	6	15		V
Junction capacitance	V _R = 0, f = 1 MHz		C _j		50		pF

Note:

 $^{^{1)}}$ In one packing unit $I_{Vmin.}/I_{Vmax.} \leq 0.5$

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OPTICAL AND ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified) TLHP440. , PURE GREEN							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous intensity 1)	I _F = 10 mA	TLHP4401	I _V	1	3		mcd
Dominant wavelength	I _F = 10 mA		λ_{d}	555		565	nm
Peak wavelength	I _F = 10 mA		λ_{p}		555		nm
Angle of half intensity	I _F = 10 mA		φ		± 30		deg
Forward voltage	I _F = 20 mA		V _F		2.4	3	V
Reverse voltage	I _R = 10 μA		V_R	6	15		V
Junction capacitance	V _R = 0, f = 1 MHz		C _j		50		pF

Note:

 $^{^{1)}}$ In one packing unit $I_{Vmin.}/I_{Vmax.} \leq 0.5$

LUMINOUS INTENSITY CLASSIFICATION					
GROUP	LIGHT INTENSITY (mcd)				
STANDARD	MIN.	MAX.			
L	1	2			
М	1.6	3.2			
N	2.5	5			
Р	4	8			
Q	6.3	12.5			
R	10	20			
S	16	32			
Т	25	50			
U	40	80			

Note:

Luminous intensity is tested at a current pulse duration of 25 ms and an accuracy of \pm 11 %.

The above type numbers represent the order groups which include only a few brightness groups. Only one group will be shipped on each bag (there will be no mixing of two groups on each bag).

In order to ensure availability, single brightness groups will not be orderable.

In a similar manner for colors where wavelength groups are measured and binned, single wavelength groups will be shipped on any one bag. In order to ensure availability, single wavelength groups will not be orderable.

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

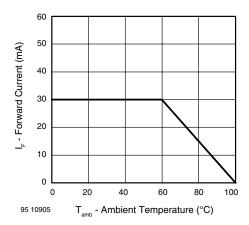


Figure 1. Forward Current vs. Ambient Temperature for InGaN

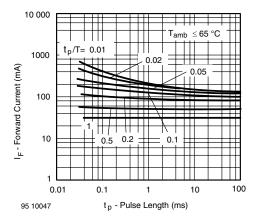


Figure 2. Forward Current vs. Pulse Length





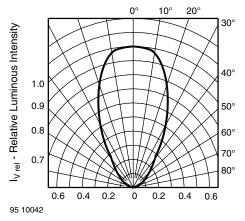


Figure 3. Rel. Luminous Intensity vs. Angular Displacement

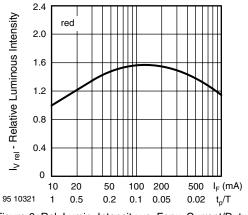


Figure 6. Rel. Lumin. Intensity vs. Forw. Current/Duty Cycle

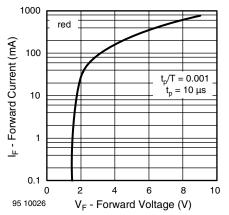


Figure 4. Forward Current vs. Forward Voltage

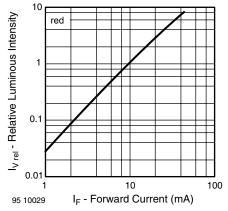


Figure 7. Relative Luminous Intensity vs. Forward Current

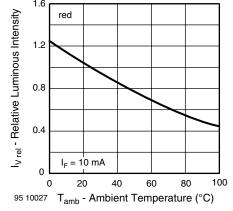


Figure 5. Rel. Luminous Intensity vs. Ambient Temperature

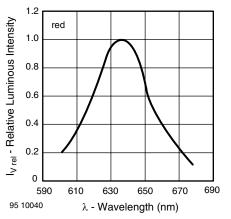


Figure 8. Relative Intensity vs. Wavelength



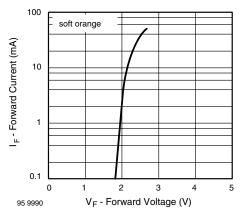


Figure 9. Forward Current vs. Forward Voltage

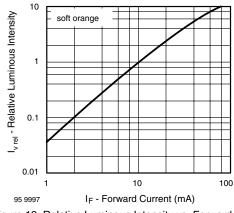


Figure 12. Relative Luminous Intensity vs. Forward Current

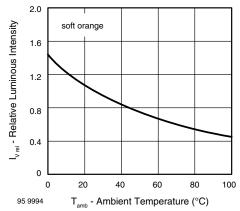


Figure 10. Rel. Luminous Intensity vs. Ambient Temperature

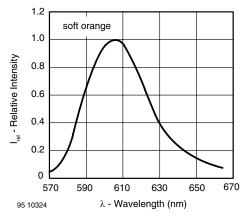


Figure 13. Relative Intensity vs. Wavelength

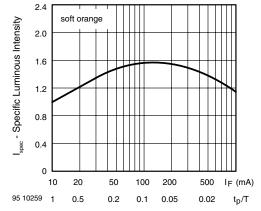


Figure 11. Rel. Lumin. Intensity vs. Forw. Current/Duty Cycle

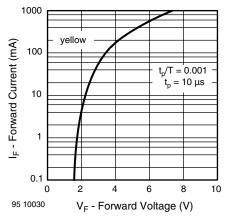


Figure 14. Forward Current vs. Forward Voltage

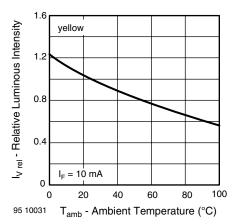


Figure 15. Rel. Luminous Intensity vs. Ambient Temperature

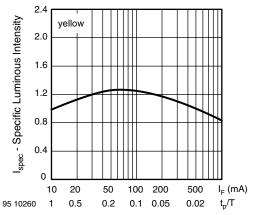


Figure 16. Rel. Lumin. Intensity vs. Forw. Current/Duty Cycle

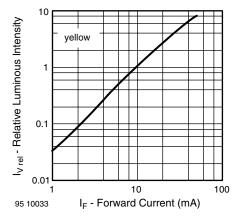


Figure 17. Relative Luminous Intensity vs. Forward Current

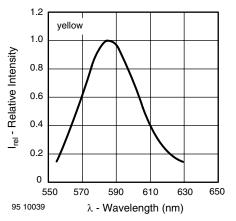


Figure 18. Relative Intensity vs. Wavelength

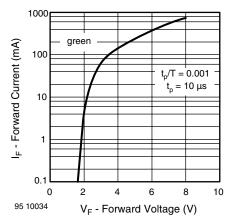


Figure 19. Forward Current vs. Forward Voltage

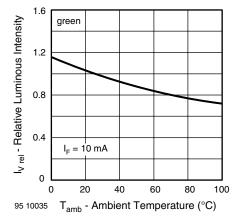


Figure 20. Rel. Luminous Intensity vs. Ambient Temperature



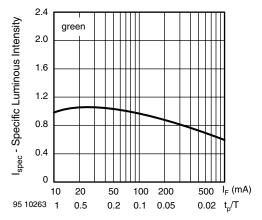


Figure 21. Specific Luminous Intensity vs. Forward Current

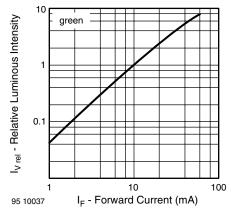


Figure 22. Relative Luminous Intensity vs. Forward Current

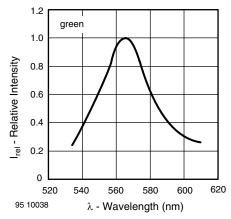


Figure 23. Relative Intensity vs. Wavelength

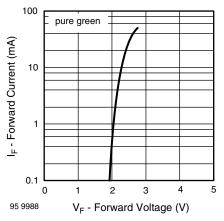


Figure 24. Forward Current vs. Forward Voltage

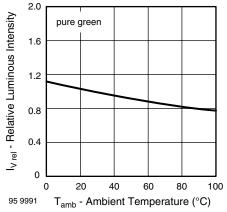


Figure 25. Rel. Luminous Intensity vs. Ambient Temperature

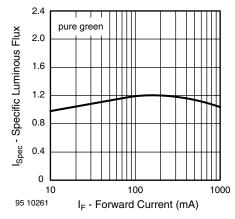


Figure 26. Specific Luminous Intensity vs. Forward Current





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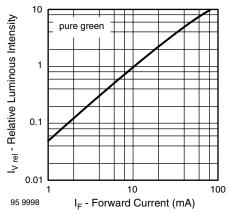


Figure 27. Relative Luminous Intensity vs. Forward Current

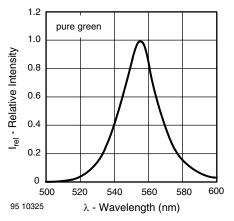
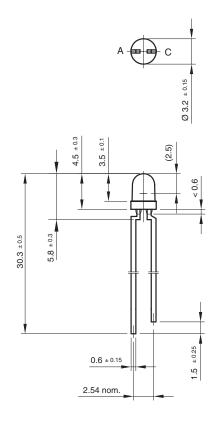
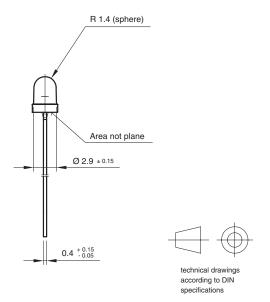


Figure 28. Relative Intensity vs. Wavelength

PACKAGE DIMENSIONS in millimeters



Drawing-No.: 6.544-5255.01-4 Issue: 7; 25.09.08 95 10913



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REEL DIMENSIONS in millimeters

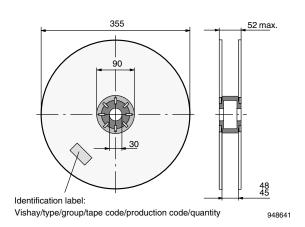


Figure 29. Reel

TAPE

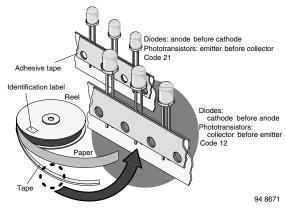


Figure 30. LED in Tape

АММОРАСК

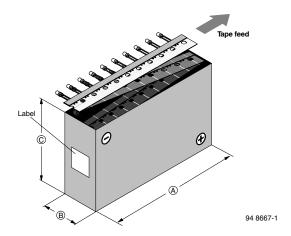


Figure 31. Tape Direction

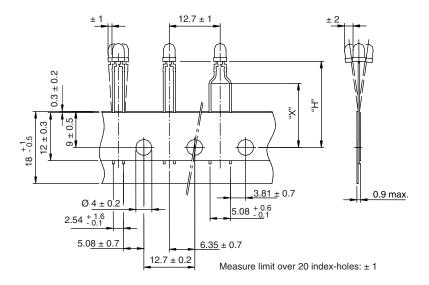
Note:

AS12Z and AS21Z still valid for already existing types BUT NOT FOR NEW DESIGN



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TAPE DIMENSIONS in millimeters



Quantity per:	Reel (Matno. 1764)
	2000

21885

Dim. "H" ± 0.5 mm	Dim. "X" ± 0.5 mm
17.3	
25.5	
22.0	
21.0	
20.0	16.0
	17.3 25.5 22.0 21.0



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Document Number: 91000 www.vishay.com Revision: 18-Jul-08